

| Form PTO 1449 (Modified) | | U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE | | ATTY DOCKET NO. 198786US-2RE | SERIAL NO. 09/891,925 | | |
|--|----|---|----------|---------------------------------|--------------------------|--|----------------------------|
| LIST OF REFERENCES CITED BY APPLICANT | | APPLICANT Mitsuhiro YANO, et al. | | | | | |
| | | FILING DATE June 27, 2001 | | GROUP 2811 | | | |
| U.S. PATENT DOCUMENTS | | | | | | | |
| EXAMINER INITIAL | | DOCUMENT NUMBER | DATE | NAME | CLASS | SUB CLASS | FILING DATE IF APPROPRIATE |
| | AA | | | | | | |
| | AB | | | | | | |
| | AC | | | | | | |
| | AD | | | | | | |
| | AE | | | | | | |
| | AF | | | | | | |
| | AG | | | | | | |
| | AH | | | | | | |
| | AI | | | | | | |
| | AJ | | | | | | |
| | AK | | | | | | |
| | AL | | | | | | |
| | AM | | | | | | |
| | AN | | | | | | |
| FOREIGN PATENT DOCUMENTS | | | | | | | |
| | | DOCUMENT NUMBER | DATE | COUNTRY | TRANSLATION | | |
| | AQ | 04-212468 | 08/04/92 | JAPAN W/ENGLISH ABSTRACT | YES | NO | XX |
| | AP | 62-073766 | 04/04/87 | JAPAN W/ENGLISH ABSTRACT | | | XX |
| | AQ | 0 091 079 | 10/12/83 | EUROPE | XX | | |
| | AR | 02-153570 | 06/13/90 | JAPAN W/ENGLISH ABSTRACT | | | XX |
| | AS | | | | | | |
| | AT | | | | | | |
| | AU | | | | | | |
| | AV | | | | | | |
| OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.) | | | | | | | |
| | AW | Richard W. COEN, et al., "A High-Performance Planar Power MOSFET", IEEE Transactions on Electron Devices, Vol. ED-27, no. 2, February 1980, pages 340-343 | | | | | |
| | AX | | | | | | |
| | AY | | | | | | |
| | AZ | | | | | <input type="checkbox"/> Additional References sheet(s) attached | |
| Examiner | | | | | | Date Considered | |
| *Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | | | | | | | |